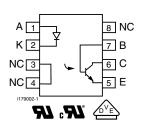


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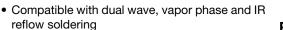
Optocoupler, Phototransistor Output, with Base Connection in SOIC-8 Package





FEATURES

- Isolation test voltage, 4000 V_{RMS}
- Industry standard SOIC-8 surface mountable package









RoHS COMPLIANT

DESCRIPTION

The IL211AT, IL212AT, IL213AT are optically coupled pairs with a gallium arsenide infrared LED and silicon NPN phototransistor. Signal information, including a DC level, can be transmitted by the device while maintaining a high degree of electrical isolation between input and output.

The IL211AT, IL212AT, IL213AT comes in a standard SOIC-8 small outline package for surface mounting which makes it ideally suited for high density applications with limited space. In addition to eliminating through-holes requirements, this package conforms to standards for surface mounted devices.

A choice of 20 %, 50 %, and 100 % minimum CTR at $I_F = 10$ mA makes these optocouplers suitable for a variety of different applications.

AGENCY APPROVALS

- UL1577, file no. E52744 system code Y
- cUL file no. E52744, equivalent to CSA bulletin 5A
- DIN EN 60747-5-2 (VDE 0884) (1)
- DIN EN 60747-5-5 (pending) (1)

Note

(1) Available upon request, as option 1

ORDERING INFORMATION					
[] L 2	1 #	А Т	SOIC-8		
AGENCY CERTIFIED/PACKAGE		CTR (%)			
AGENCY CENTIFIED/PACKAGE	10 mA				
UL, cUL	> 20	> 50	> 100		
SOIC-8	IL211AT	IL212AT	IL213AT		

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)									
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT					
INPUT									
Peak reverse voltage		V _R	6	V					
Forward continuous current		I _F	60	mA					
Power dissipation		P _{diss}	90	mW					
Derate linearly from 25 °C			1.2	mW/°C					
OUTPUT									
Collector emitter breakdown voltage		BV _{CEO}	30	V					
Emitter collector breakdown voltage		BV _{ECO}	7	V					
Collector base breakdown voltage		V_{CBO}	70	V					
I _{CMAX. DC}		I _{CMAX. DC}	50	mA					
I _{CMAX} .	t < 1 ms	I _{CMAX.}	100	mA					
Power dissipation		P _{diss}	150	mW					
Derate linearly from 25 °C			2	mW/°C					

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IL211AT, IL212AT, IL213AT

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ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)									
PARAMETER	TEST CONDITION	IDITION SYMBOL VALUE UNIT							
COUPLER									
Isolation test voltage		V _{ISO}	4000	V _{RMS}					
Total package dissipation	LED and detector	P _{tot}	240	mW					
Derate linearly from 25 °C			3.2	mW/°C					
Storage temperature		T _{stg}	-55 to +150	°C					
Operating temperature		T _{amb}	-55 to +100	°C					
Soldering time	at 260 °C		10	S					

Note

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
maximum ratings for extended periods of the time can adversely affect reliability.

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT	
INPUT								
Forward voltage	$I_F = 10 \text{ mA}$		V_{F}	1	1.3	1.5	V	
Reverse current	$V_R = 6 V$		I _R	-	0.1	100	μΑ	
Capacitance	$V_R = 0 V$		Co	-	13	-	pF	
OUTPUT								
Collector emitter breakdown voltage	$I_C = 10 \mu A$		BV _{CEO}	30	-	-	٧	
Emitter collector breakdown voltage	$I_E = 10 \mu A$		BV _{ECO}	7	-	-	V	
Collector dark current	$V_{CE} = 10 \text{ V}$		I _{CEO}	ı	5	50	nA	
Collector emitter capacitance	$V_{CE} = 0 V$		C _{CE}	-	10		pF	
COUPLER								
Saturation voltage, collector emitter	$I_F = 10 \text{ mA}$		V _{CEsat}	1	-	0.4	V	
Isolation test voltage	1 s		V _{ISO}	4000	-	-	V_{RMS}	
Capacitance (input to output)			C _{IO}	-	0.5	50	pF	
Resistance (input to output)			R _{IO}	-	100	-	GΩ	
Collector emitter breakdown voltage	$I_C = 10 \mu A$		BV _{CEO}	30	-	-	V	

Note

• Minimum and maximum values were tested requirements. Typical values are characteristics of the device and are the result of engineering evaluations. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO								
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT	
		IL211AT	CTR	20	50	-	%	
Current transfer ratio	$I_F = 10 \text{ mA}, V_{CE} = 5 \text{ V}$	IL212AT	CTR	50	80	-	%	
		IL213AT	CTR	100	130	-	%	

SWITCHING CHARACTERISTICS							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Switching time	I_C = 2 mA, R_L = 100 Ω , V_{CC} = 10 V		t _{on} , t _{off}	-	3	-	μs



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SAFETY AND INSULATION RATINGS									
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT			
Climatic classification	According to IEC 68 part 1		-	55 / 100 / 21	-				
Comparative tracking index		CTI	175	-	399				
V _{IOTM}			6000	-	-	V			
V _{IORM}			560	-	-	V			
P _{SO}			-	-	350	mW			
I _{SI}			-	-	150	mA			
T _{SI}			-	-	165	°C			
Creepage distance			4	-	-	mm			
Clearance distance			4	-	-	mm			
Insulation thickness			0.2	-	-	mm			

Note

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

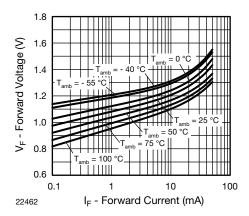


Fig. 1 - Forward Voltage vs. Forward Current

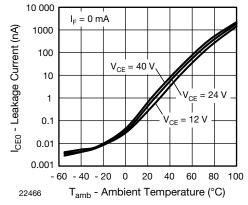


Fig. 3 - Leakage Current vs. Ambient Temperature

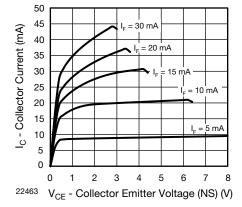


Fig. 2 - Collector Current vs. Collector Emitter Voltage (non-saturated)

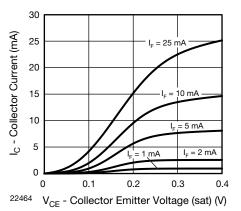


Fig. 4 - Collector Current vs. Collector Emitter Voltage (saturated)

As per IEC 60747-5-2, § 7.4.3.8.1, this optocoupler is suitable for "Safe Electrical Insulation" only within the safety ratings. Compliance with
the safety ratings shall be ensured by means of protective circuits.



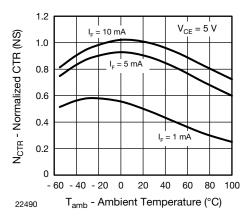


Fig. 5 - Normalized CTR (non-saturated) vs. Ambient Temperature

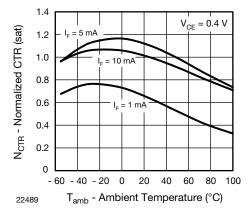


Fig. 6 - Normalized CTR (saturated) vs. Ambient Temperature

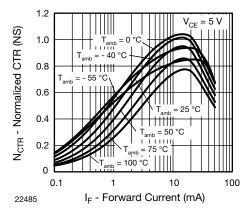


Fig. 7 - Normalized CTR (non-saturated) vs. Forward Current

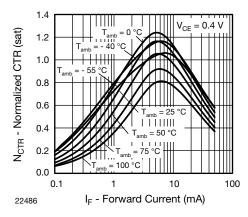


Fig. 8 - Normalized CTR (saturated) vs. Forward Current

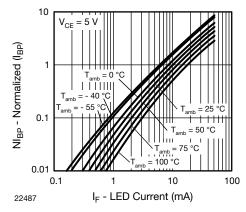


Fig. 9 - Normalized Photocurrent vs. LED Current

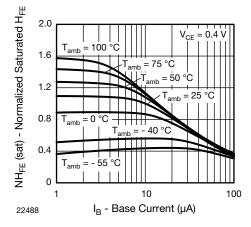


Fig. 10 - Normalized Saturated H_{FE} vs. Base Current

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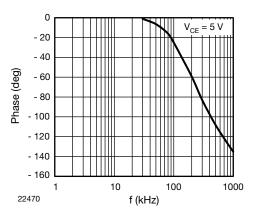


Fig. 11 - F_{CTR} vs. Phase Angle

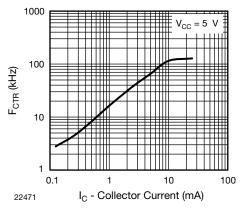


Fig. 12 - F_{CTR} vs. I_C

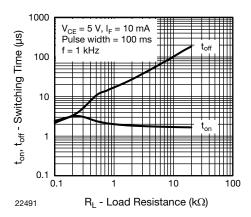


Fig. 13 - Switching Time vs. Load Resistance

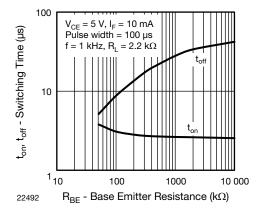
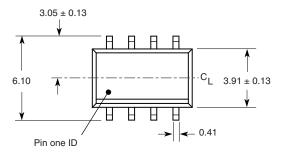


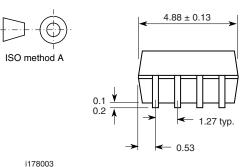
Fig. 14 - Switching Time vs. Base Emitter Resistance

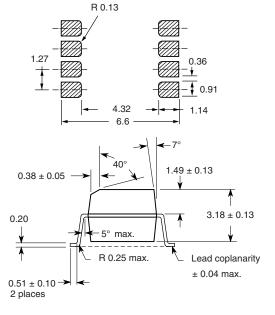


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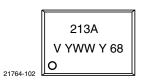
PACKAGE DIMENSIONS in millimeters







PACKAGE MARKING (example)



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